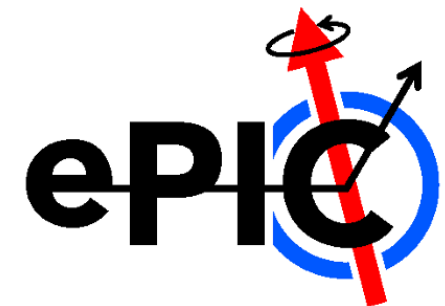


Sensor testing updates at UCSC

Simone Mazza (SCIPP, UC Santa Cruz)



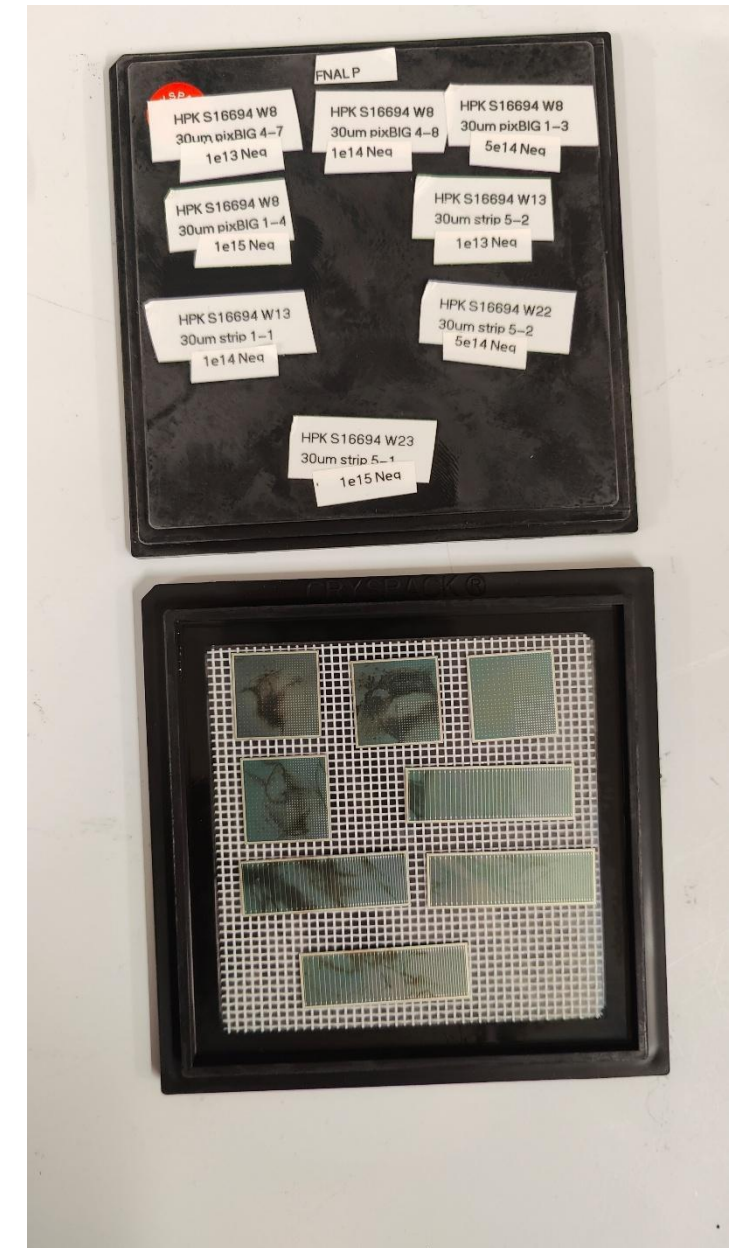
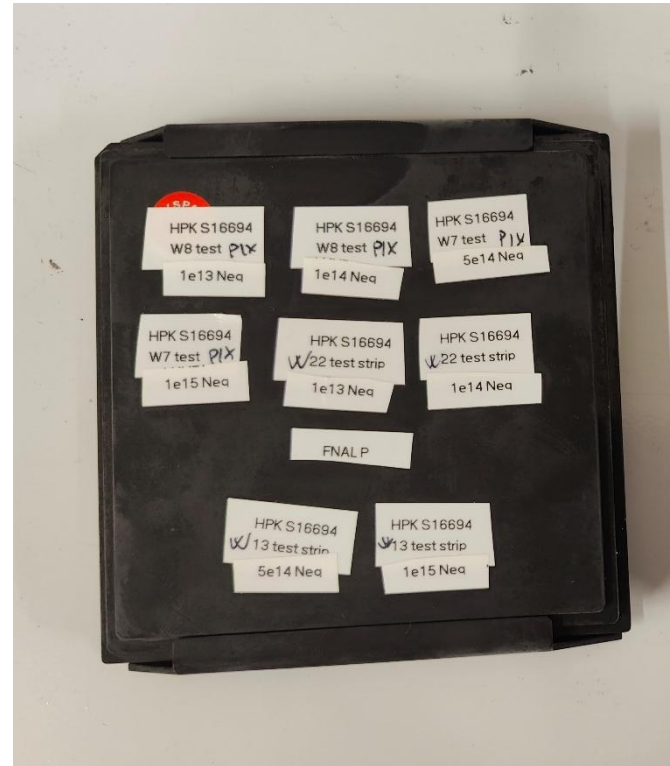
Update on sensor testing at UCSC

- Comparison of HPK devices from 2023, 2024 and 2025 productions to investigate time resolution loss
 - Laser TCT
 - Beta source telescope (see next contribution)
- Testing of new batch of irradiated devices (2 weeks ago)
 - Irradiated at FNAL with low to high fluence
 - Full size sensors irradiated
 - Plans: IV/CV/N⁺ change/Laser TCT
- Test of new double metal HPK strip sensor
 - Laser TCT

Irradiated full sensors

FNAL irradiated sensors

- Irradiated full size sensors and test structures at FNAL
- 1e13, 1e14, 5e14, 1e15Neq
- Important to check effect on large devices:
 - Increase of leakage current (relevant)
 - Performance change (likely not for ePIC)
 - Secondary effects
- Testing ongoing
 - IV/CV almost done
 - N+ resistivity from test structures
 - Laser TCT
- Also testing extremely irradiated devices
- Not of interest for ePIC, towards FCC

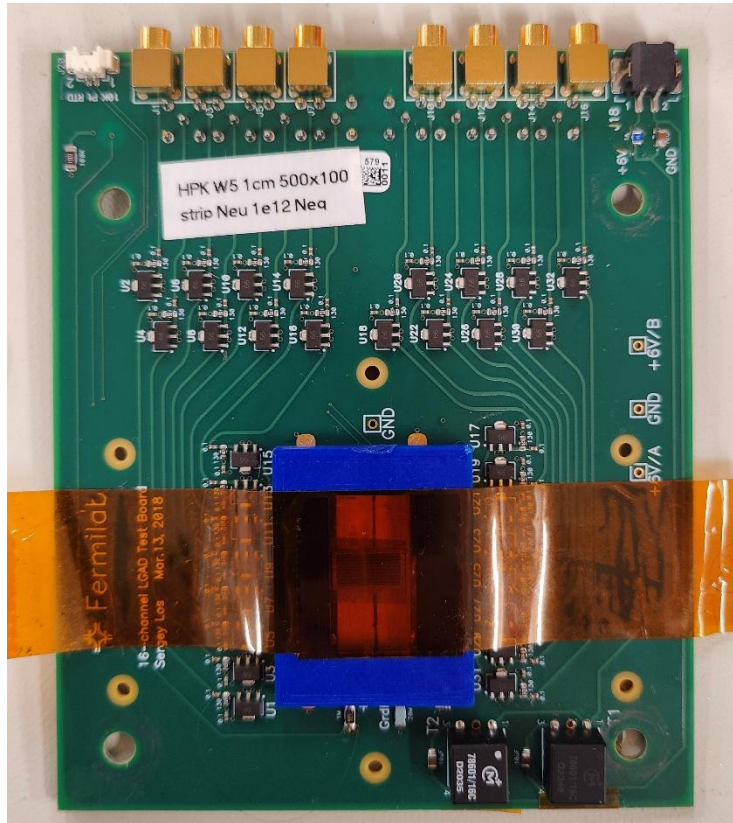


Strip sensor 2023, 2024, 2025 comparison

Comparison of HPK devices from 2023, 2024 and 2025

- Laser TCT data comparison, using same laser power, maximum voltage
 - Note: same laser power is not same injected charge (variations occur)
 - Scans over a single strip electrode

2023



2024 (S16694)

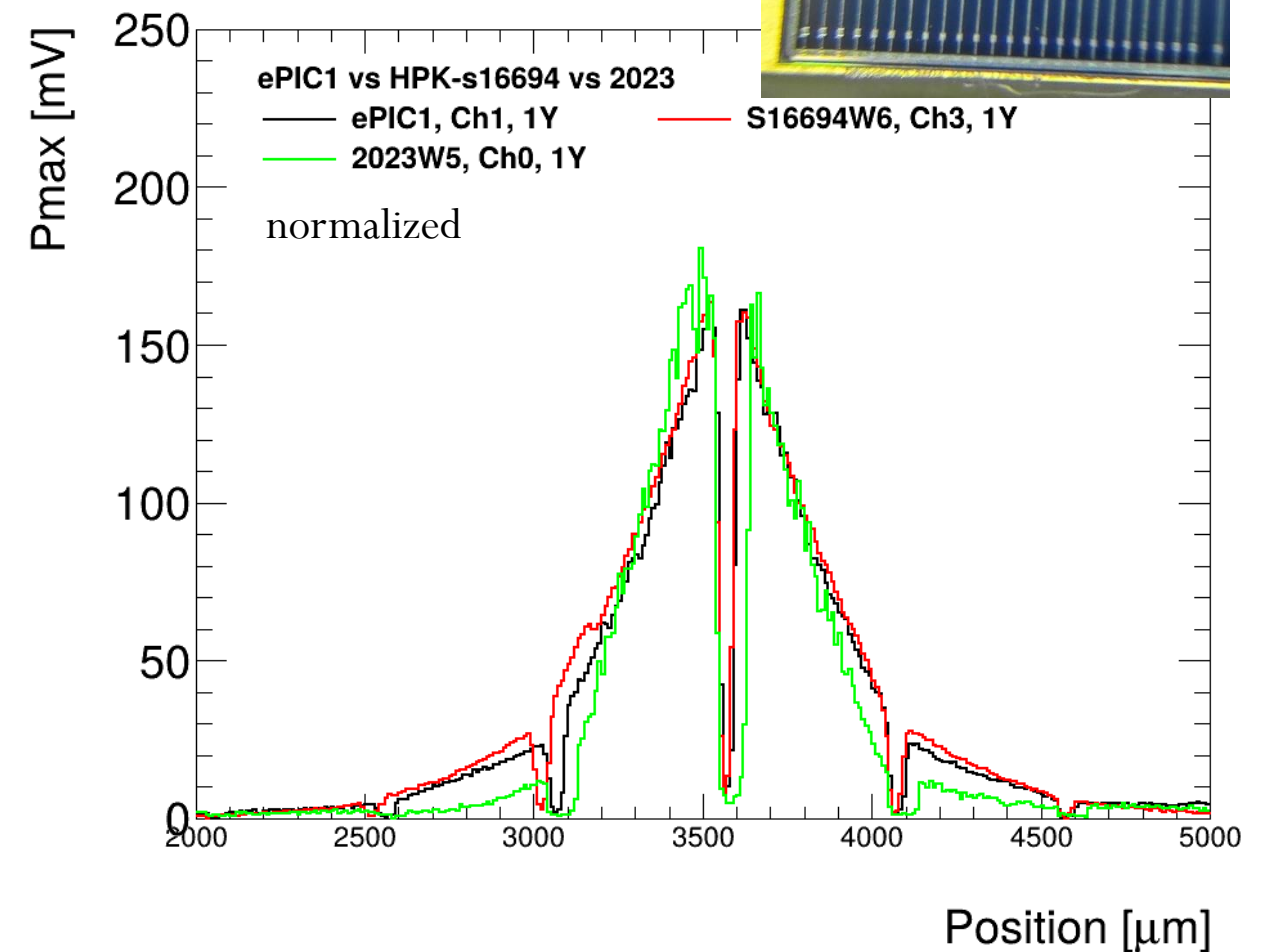
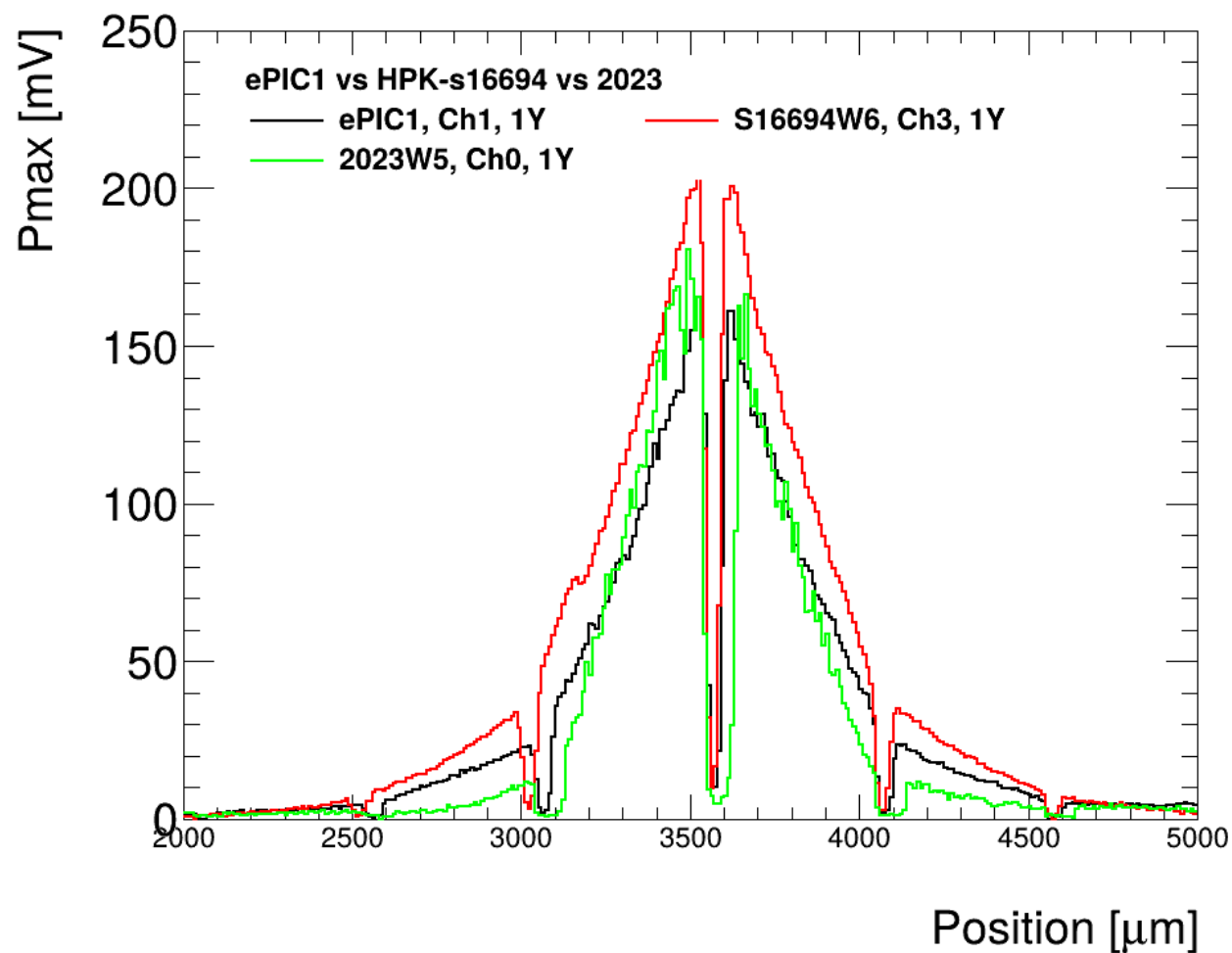
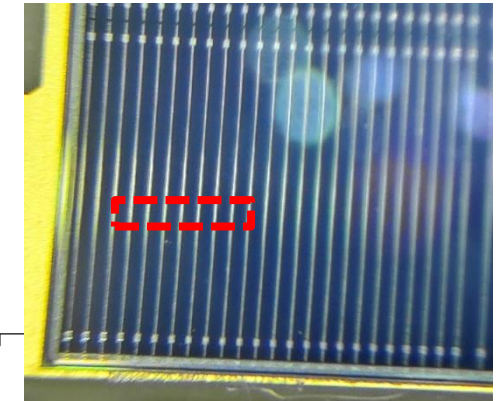


2025 (ePIC1)



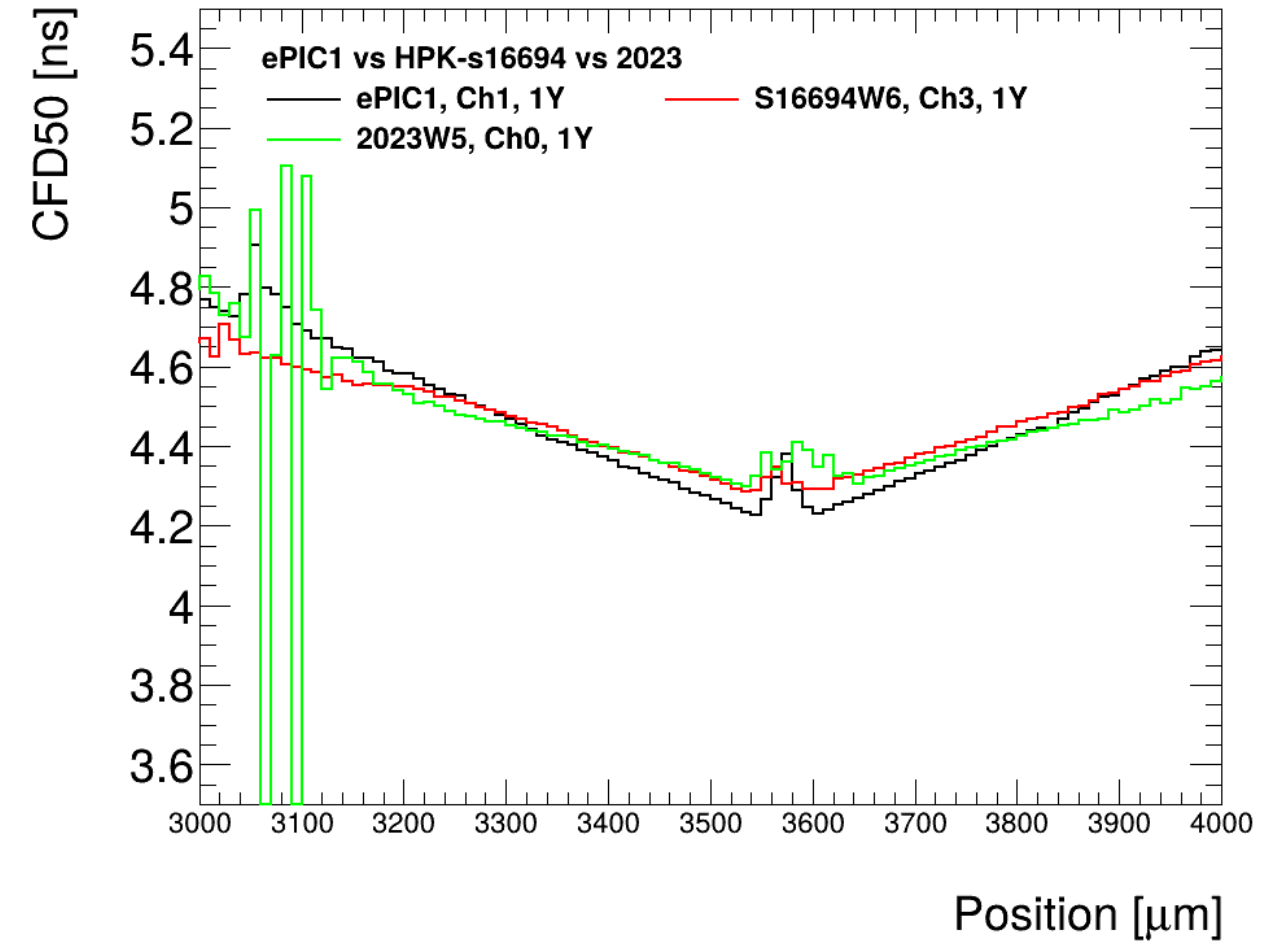
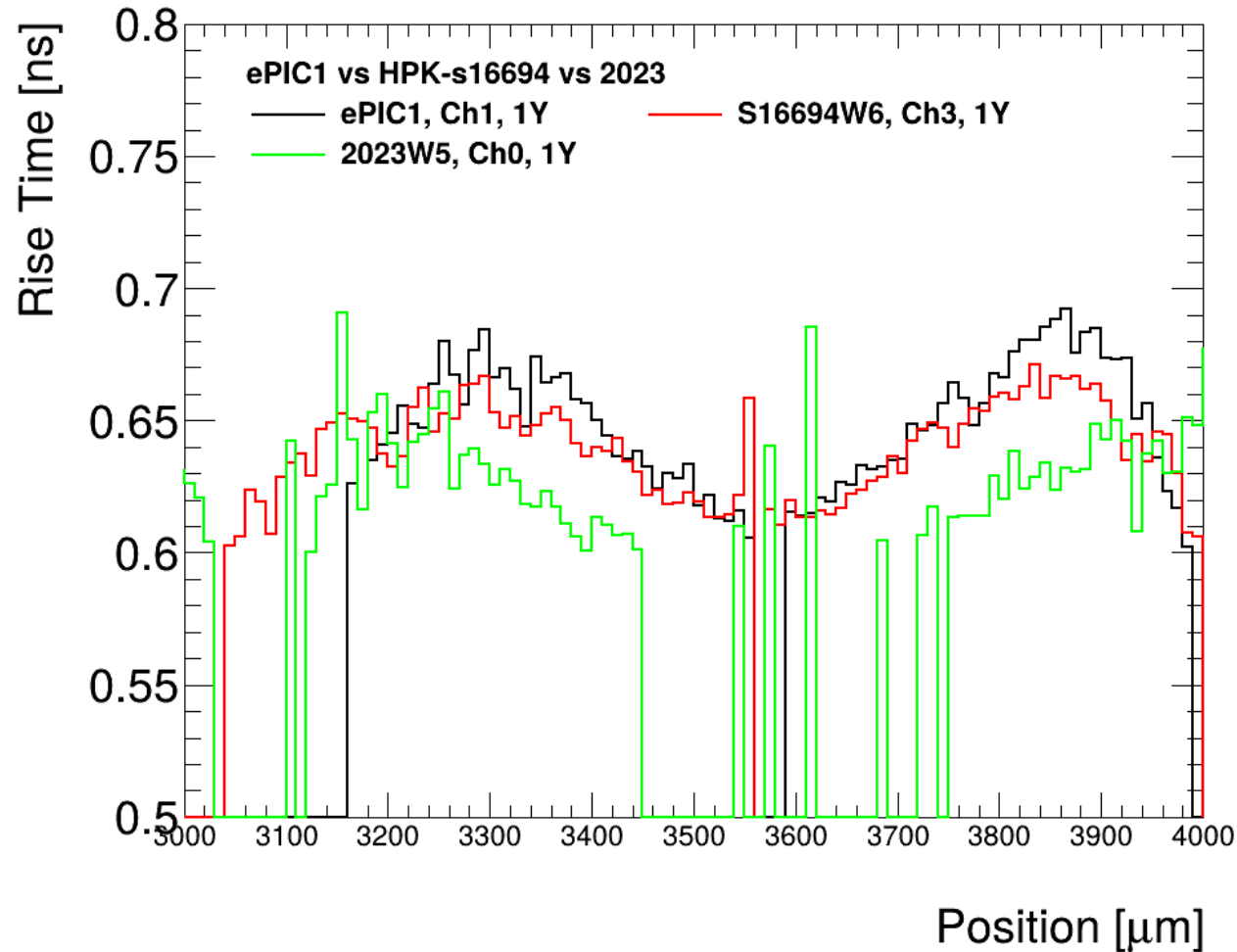
Comparison of HPK devices from 2023, 2024 and 2025

- Laser TCT data comparison, using same laser power, maximum voltage
 - Note: same laser power is not same injected charge (variations occur)



Comparison of HPK devices from 2023, 2024 and 2025

- Laser TCT data comparison, using same laser power, maximum voltage
 - Note: same laser power is not same injected charge (variations occur)

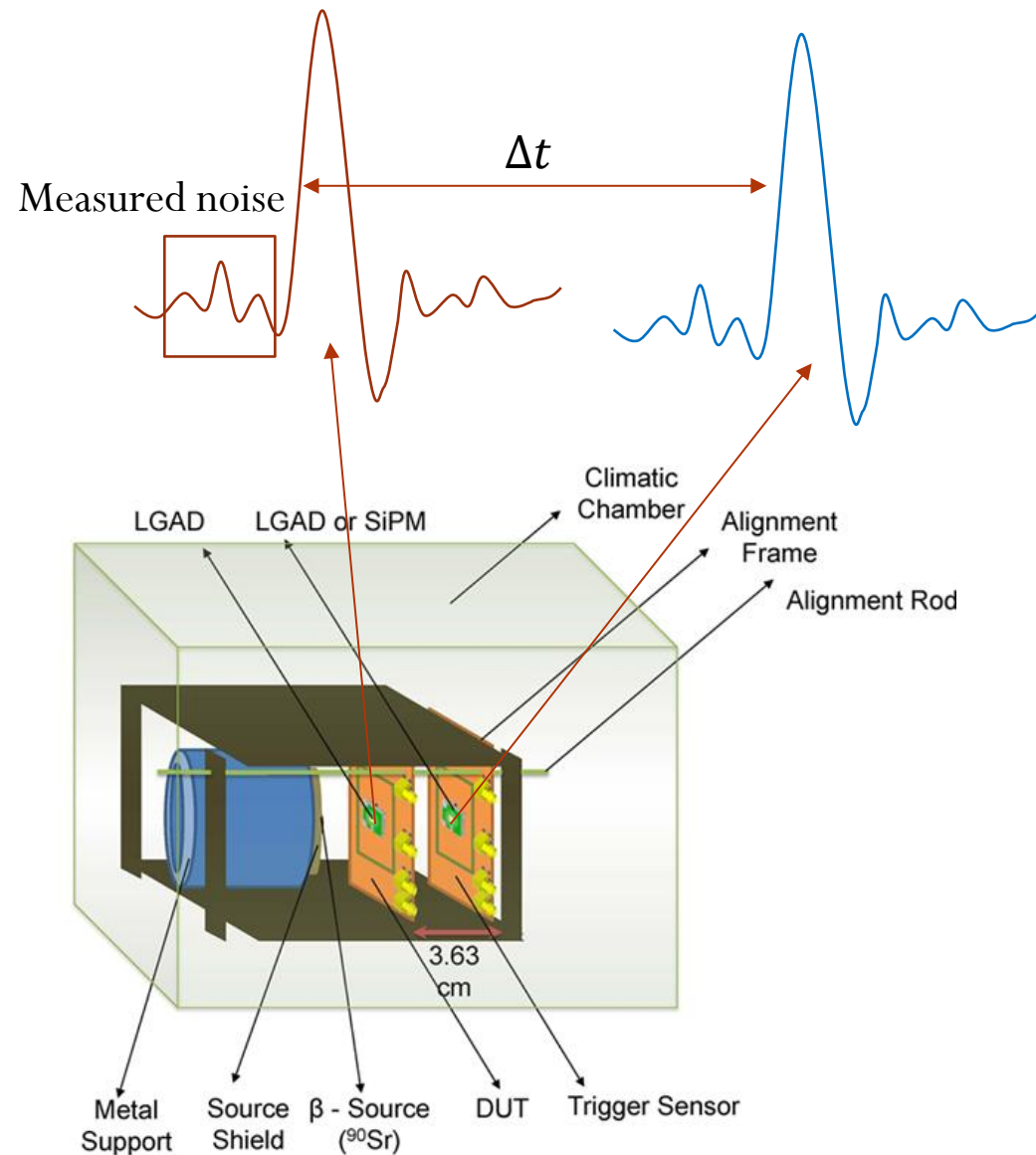


Comparison of HPK devices from 2023, 2024 and 2025

- Laser TCT data comparison, using same laser power, maximum voltage
 - Note: same laser power is not same injected charge (variations occur)
- Comments:
 - Using the same laser power we get roughly the same signal for the three devices
 - Rise time is comparable
 - Time of arrival correction is comparable
- Notes:
 - The 2023 sensor has the same thickness, N⁺ resistivity and oxide as S16694
 - The 2025 has a different oxide thickness (thicker)
 - The 2024 and 2025 sensors have the same geometry 500x50um
 - The 2023 is 500x100um, I can't find a 500x50um anymore
 - The 2023 is also very lightly irradiated, but that should not affect performance

Sensor testing – Sr90 telescope

Details: S.M. Mazza et al. arXiv:1804.05449



- Same sensors tested with beta source with coincidence trigger
- Two sensors are aligned with a beta source
 - DUT (Device Under Test) to characterize: **on 16ch board, readout 3 strips. Use to reconstruct event position**
 - Trigger with known performance, **1mm size**
- Sensors mounted on fast amplifier boards ($\sim 2\text{GHz}$) and read out by a fast oscilloscope (2GHz, 20Gs)
- **Collected charge**
- **Time resolution:** sigma of time difference between trigger sensor (with known time resolution) and DUT,
- **Gain:** collected charge divided by collected charge in same thickness PiN
- **Data taking still ongoing**
- **See next talk!**

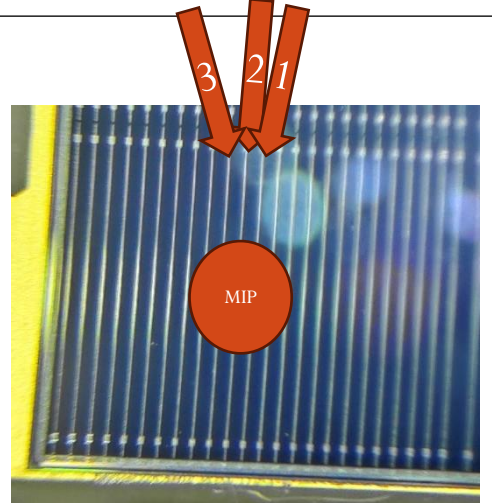
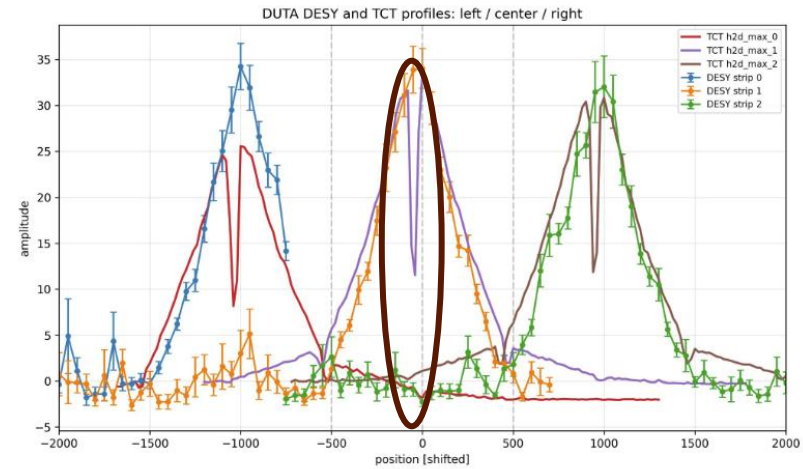
Pmax under center strip

“Dumb” quick analysis: select events under strip 2 by assuming same signal from Strip 1 and strip 3

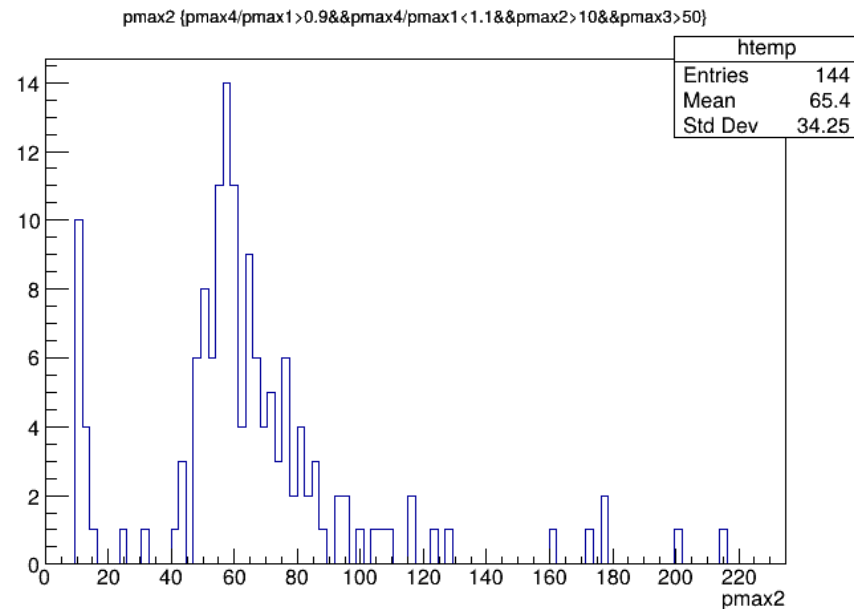
Laser TCT was off by $\sim 50\%$ of 1 MIP

Signal for 2024 and 2025 $\sim$ same, 2023 has lower signal?

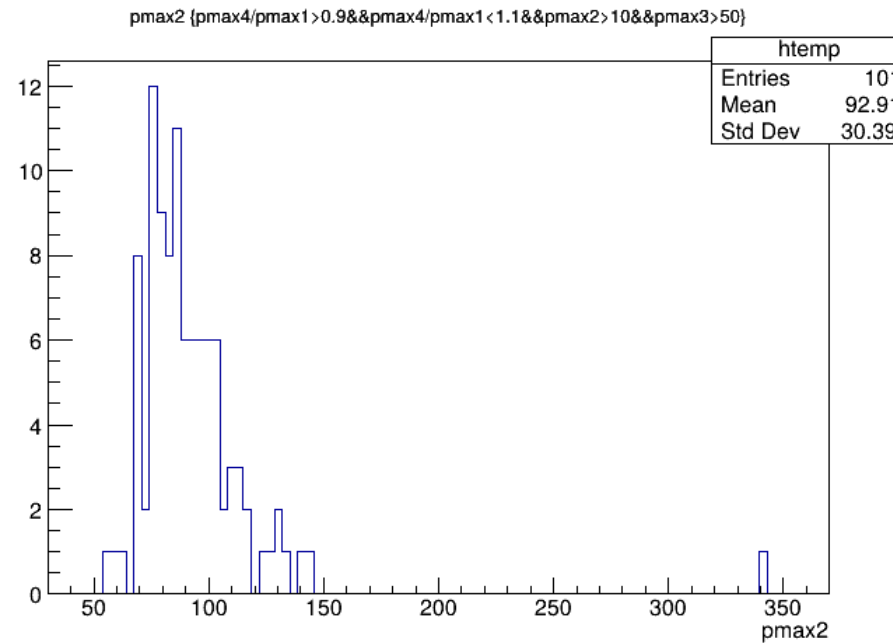
Trying higher voltage for 2023 (190V $\rightarrow$ 210V) data taking ongoing



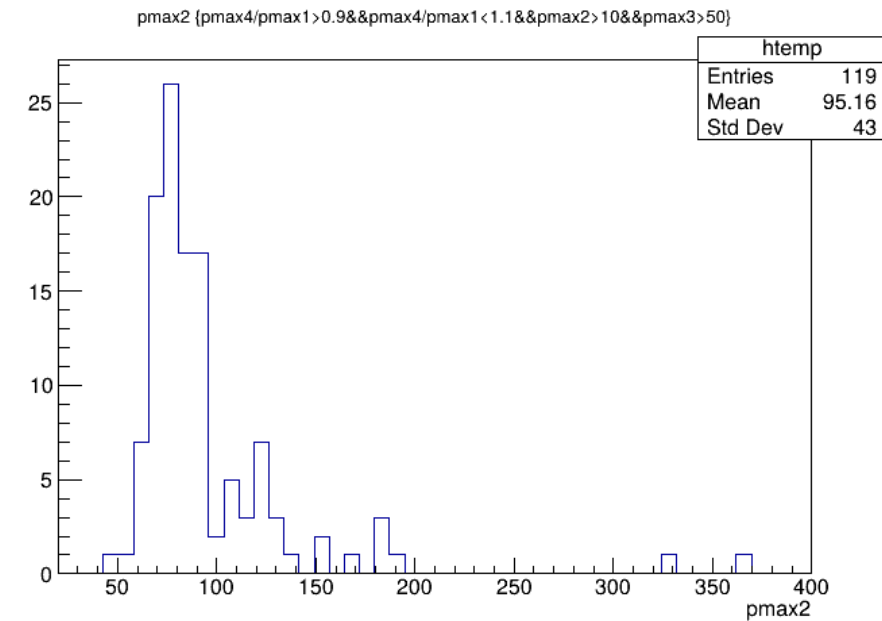
2023



2024



2025

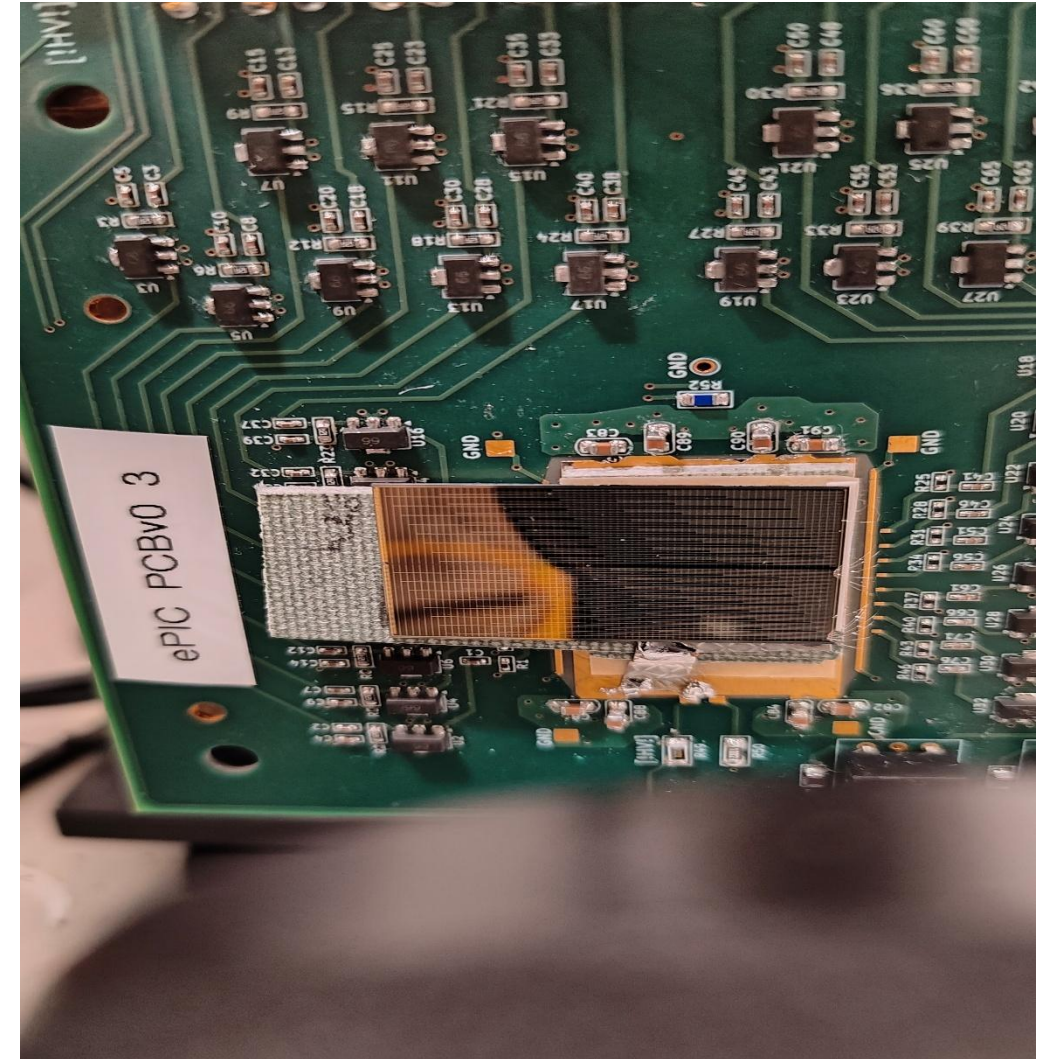
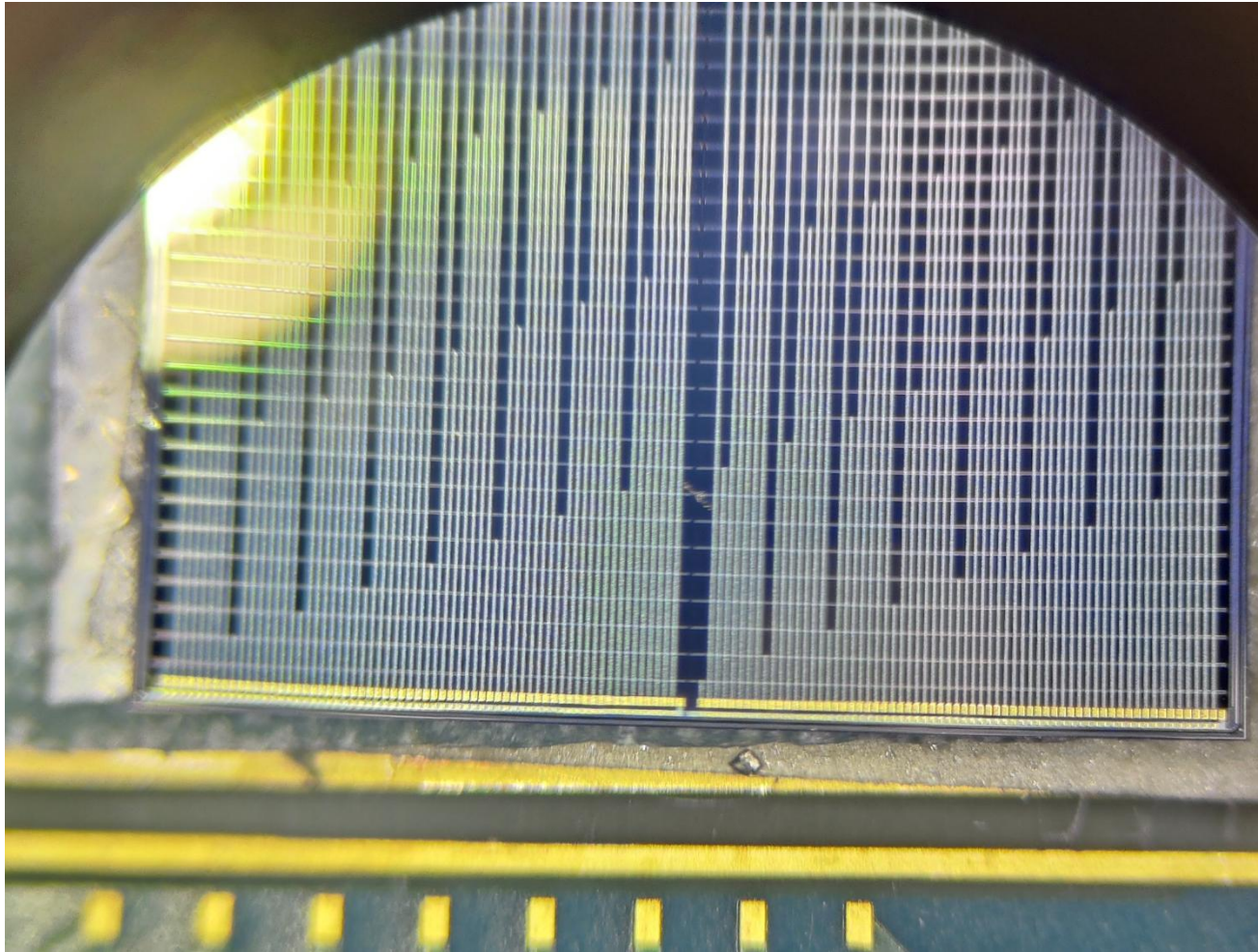


```
wfm->Draw("pmax2", "pmax4/pmax1>0.9&pmax4/pmax1<1.1&pmax2>10&pmax3>50")
```

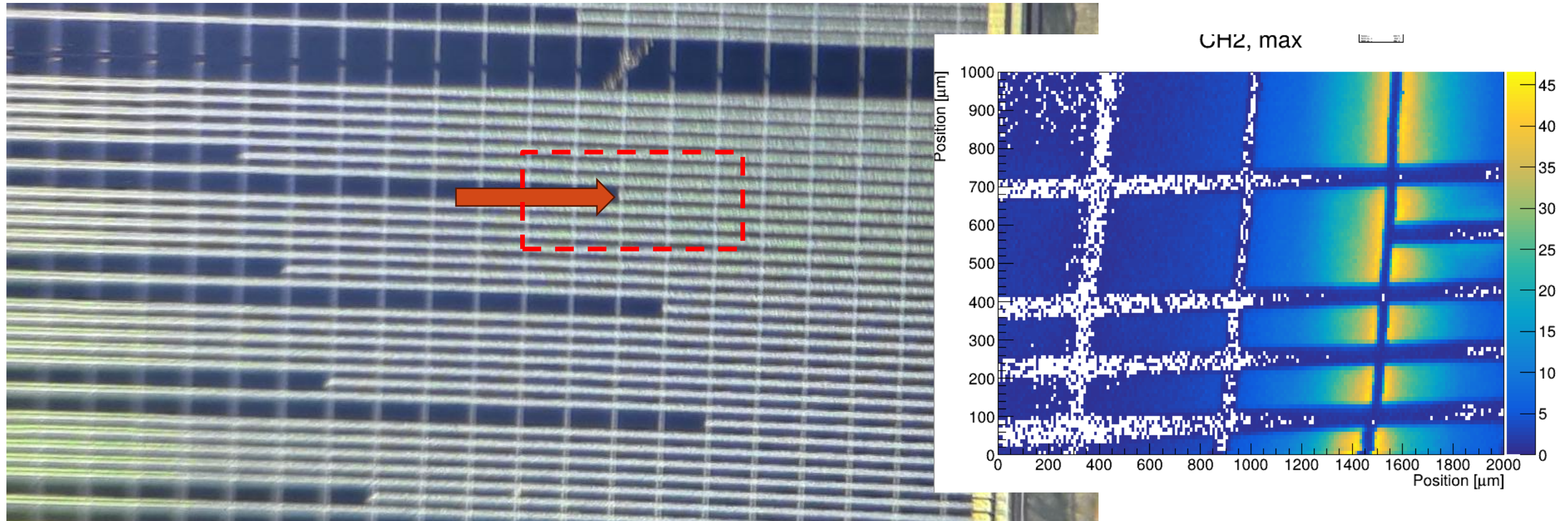
Pmax3 is trigger

Double metal sensor

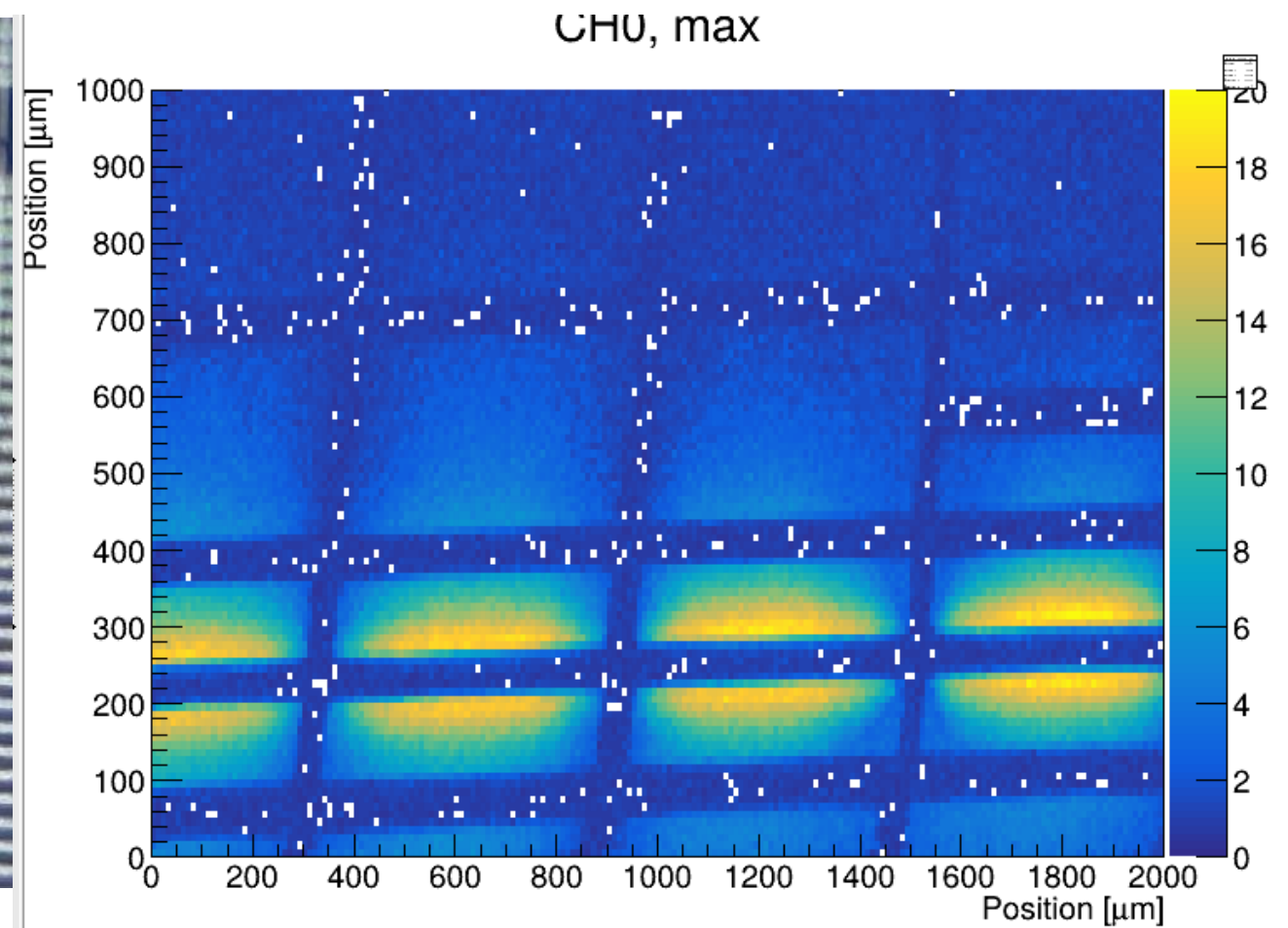
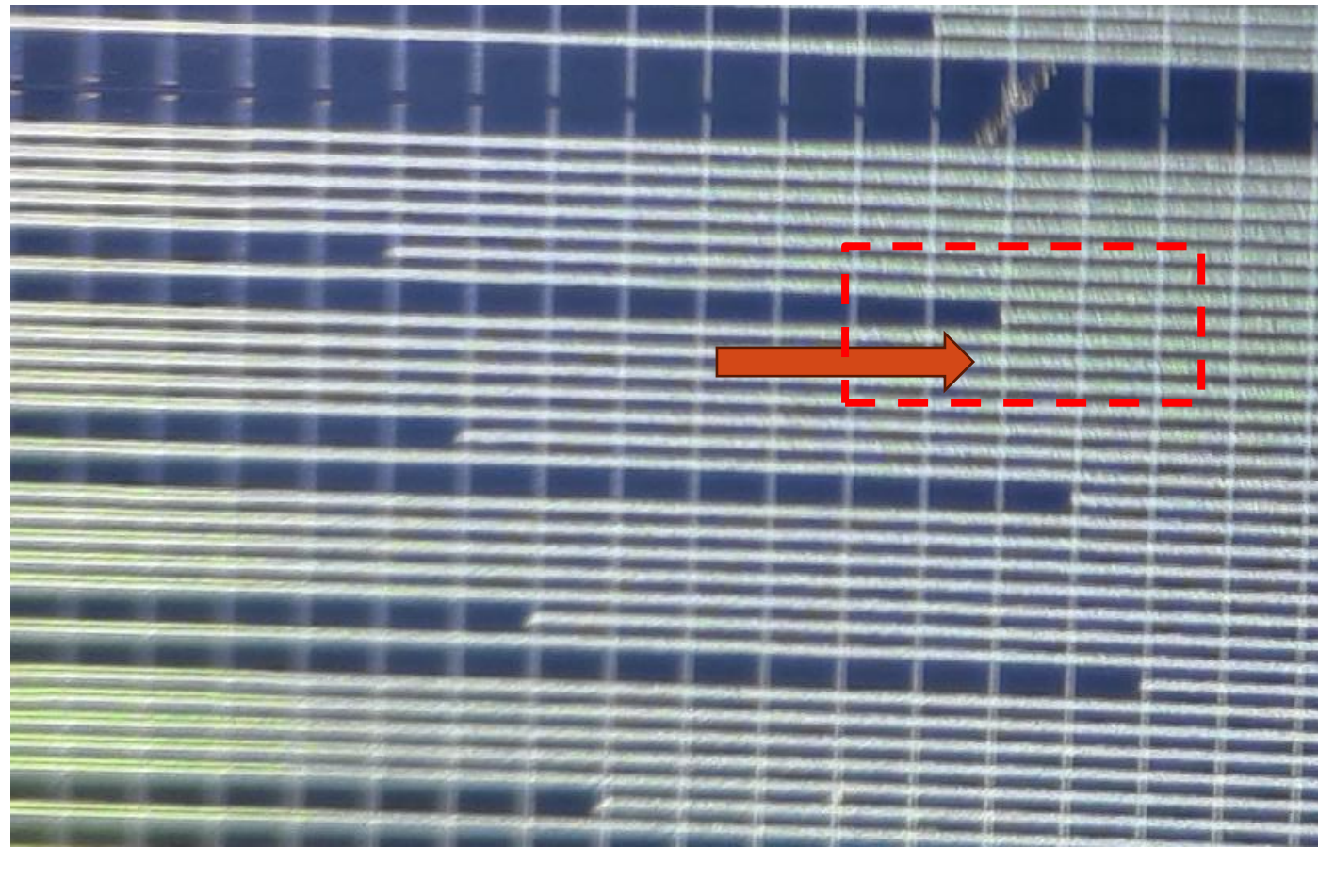
New double metal sensor



New double metal sensor



New double metal sensor

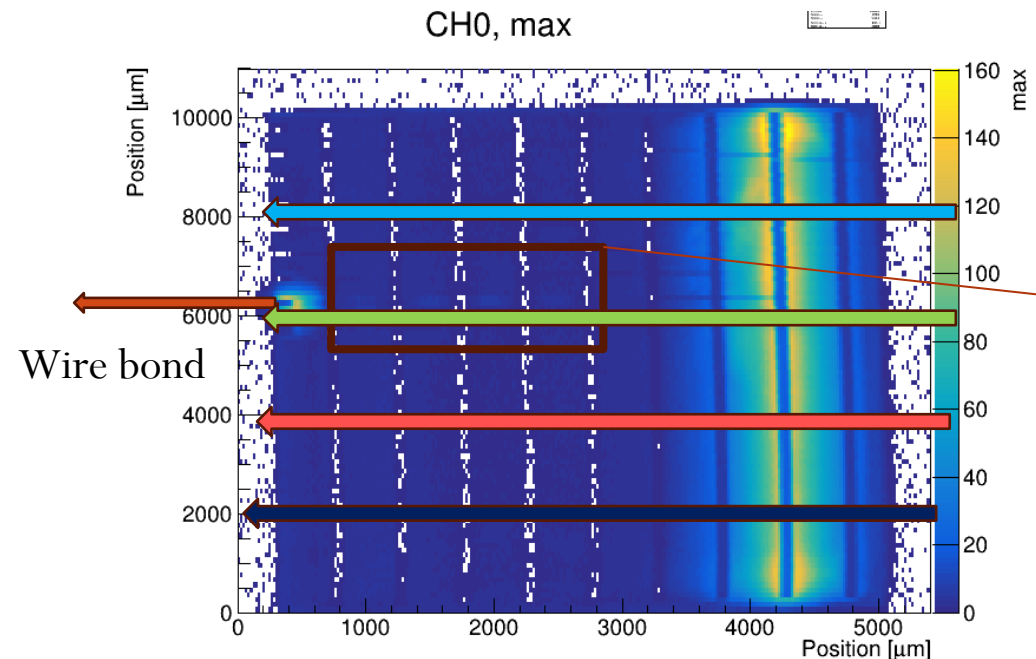
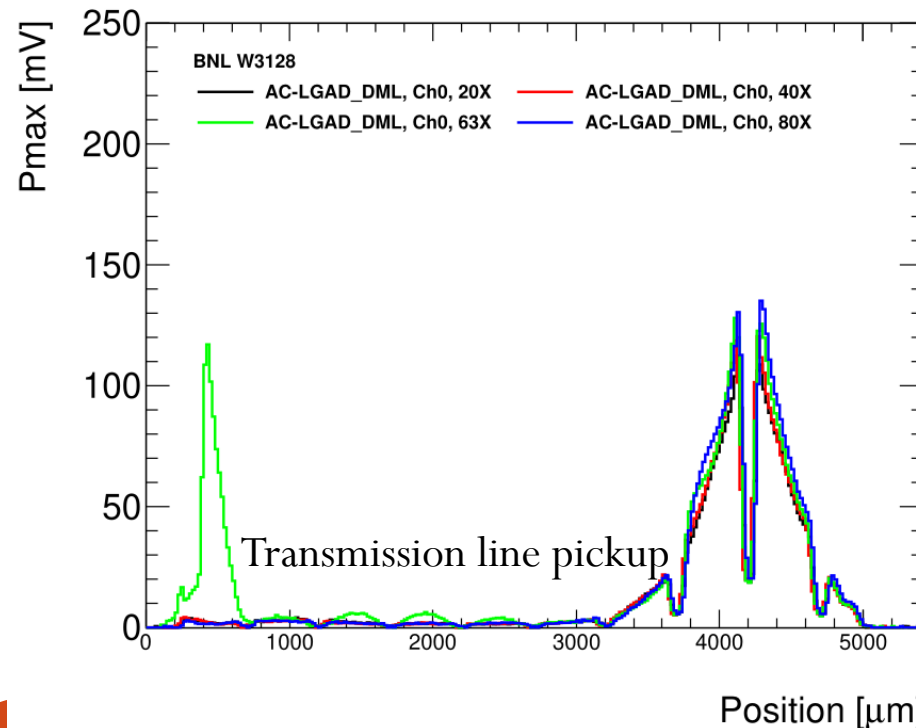
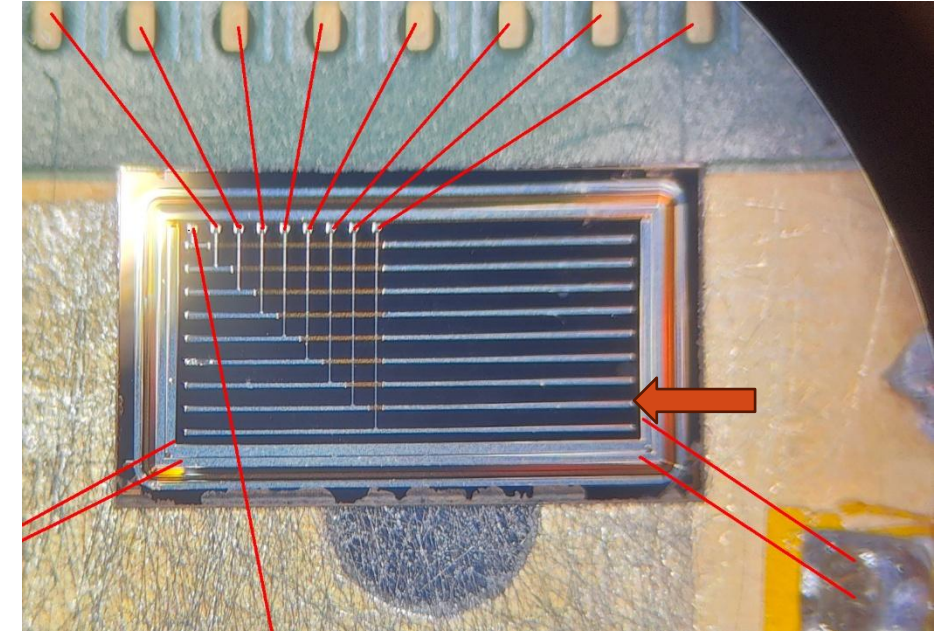


New double metal sensor

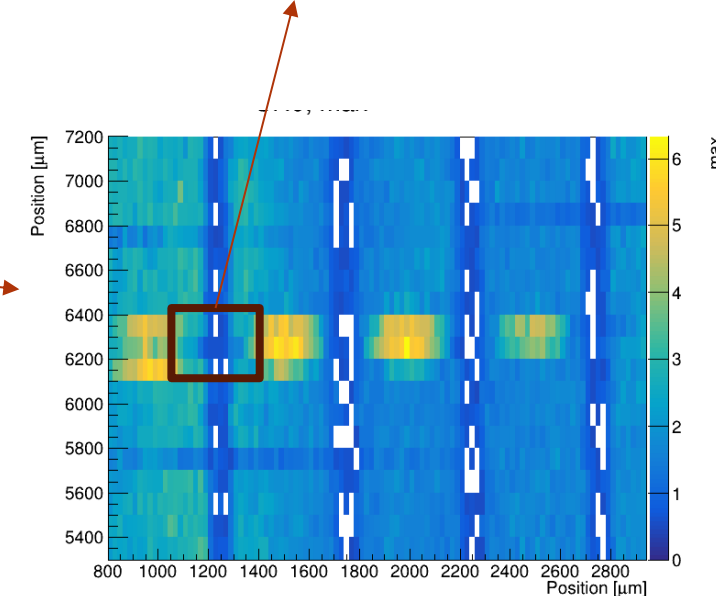
- Transmission lines pick up a lot of signal, around $\frac{1}{2}$ of real electrodes
- Probably too wide or 2nd oxide too thin
- BNL device had much less transmission line pickup ($\sim 4\%$)
- Analysis ongoing, probably need better connection scheme

DML AC-LGADs

- Proof of principle works! Behaves as standard AC-LGAD
- Pickup of the cross strip is minimal, extra pickup at the bonding pad
 - Pickup on the line is $\sim 4\%$
 - Cross talk with perpendicular strip hard to test with laser
- Behavior across the strip is homogeneous
 - Both Pmax and rise time are ok
- **Signal delays are complex to correct for**
 - Large delays due to transmission lines
 - Signal propagation in strip and transmission line is different



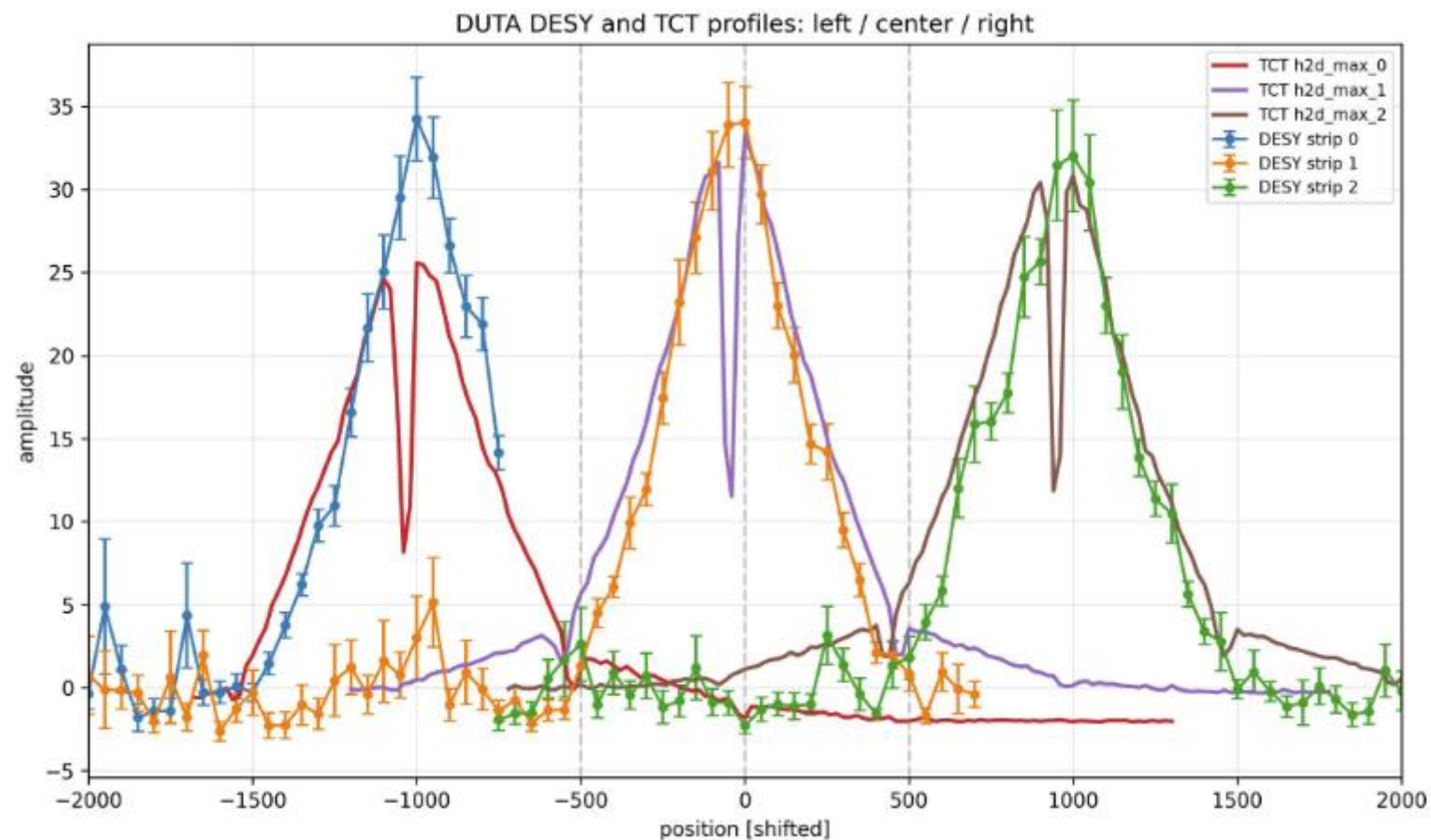
Can't test crosstalk under metal



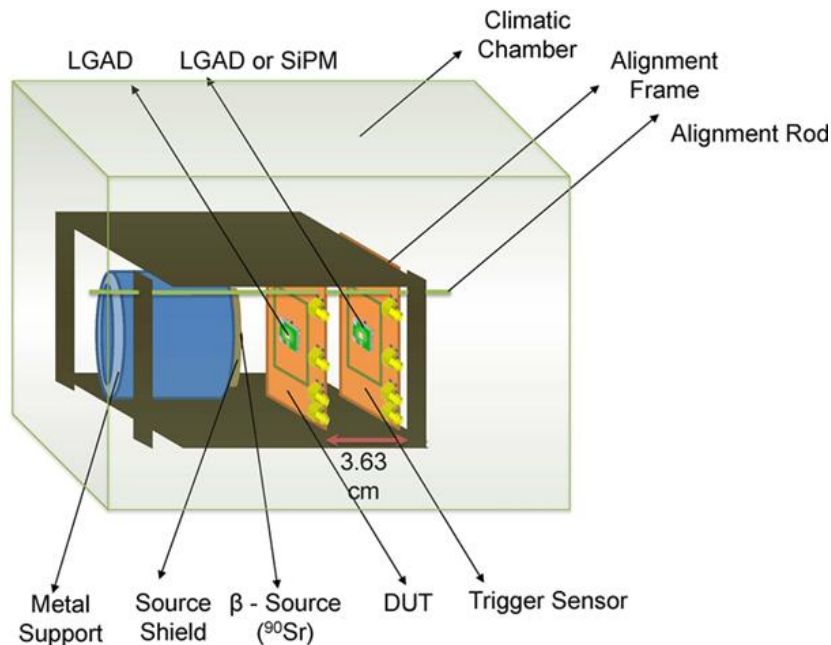
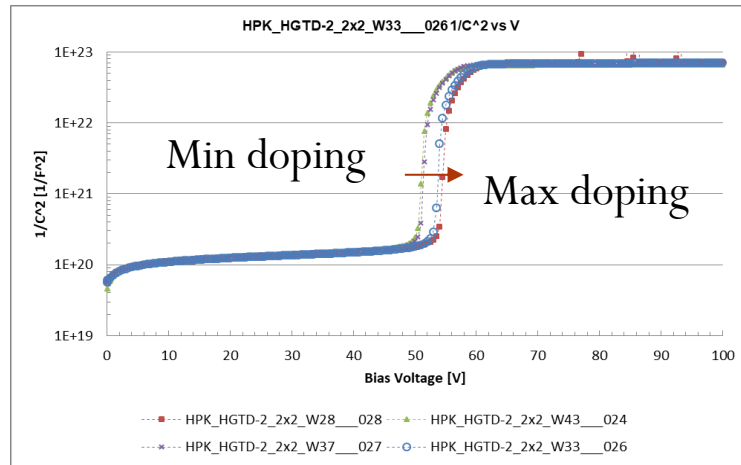
Backup

Laser TCT and testbeam comparison

- Pretty good agreement!



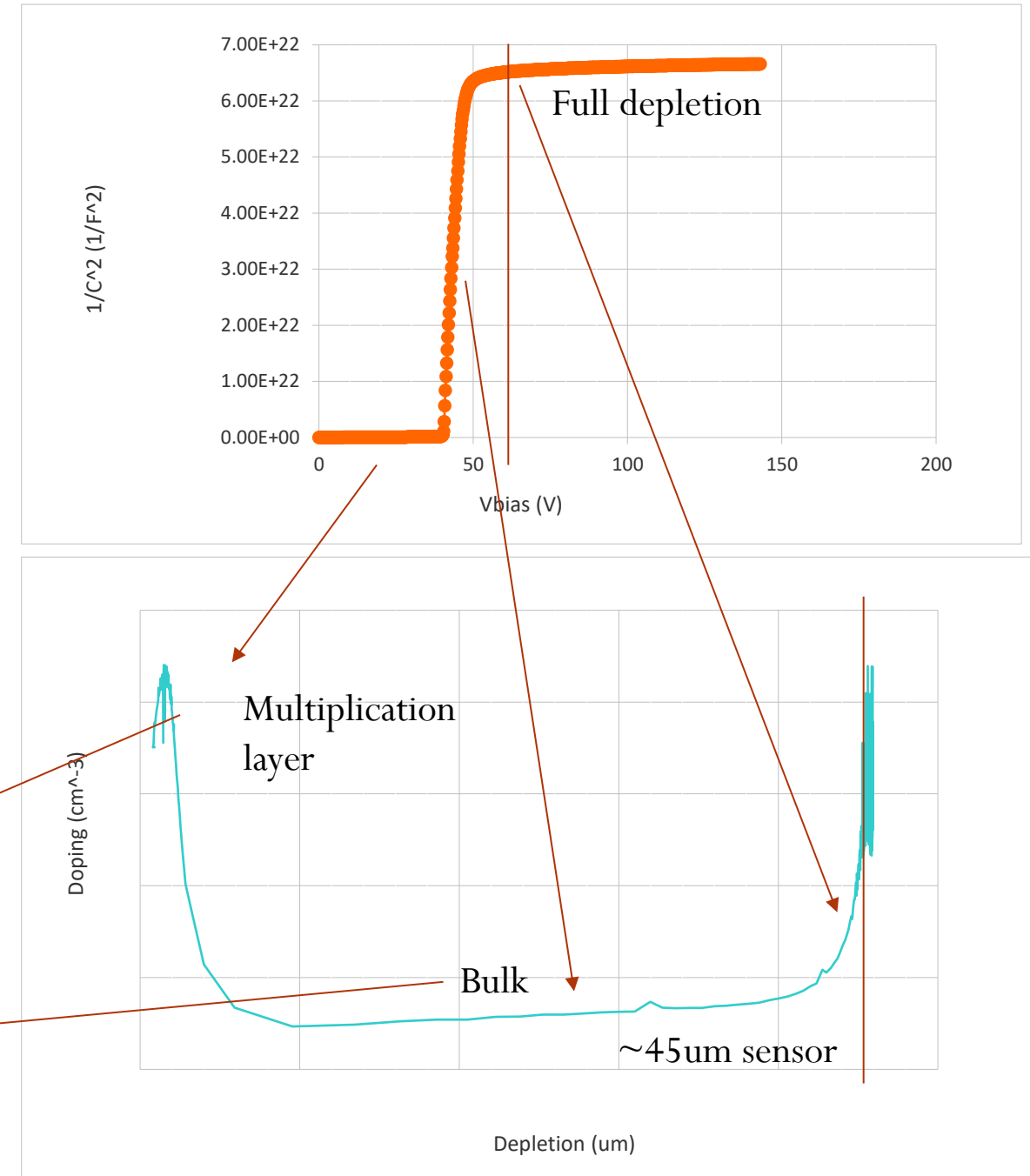
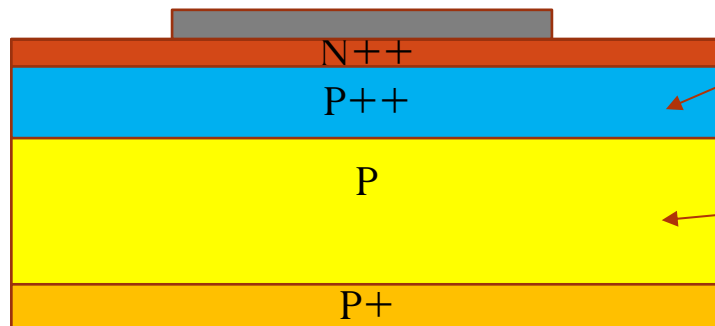
Sensor testing –probe station, charge collection



- **Probe station electrical testing**
 - Current of voltage (IV) and Capacitance over voltage (CV)
 - CV is used to probe the doping profile of the gain layer
- **Laboratory charge collection**
 - Using MiP electrons from a Sr90 β -source (β -telescope)
 - Signal shape, noise, **collected charge**, gain, **time resolution**
 - Using Alpha source in vacuum (Am237), ~ 100 MIPs deposition
 - Using X-ray gun
- **Laser TCT studies**
 - IR laser mimics a MiP response and allows charge injection as a function of position
 - Particularly useful to test arrays and AC-LGADs (see later)
- **Test beam at facilities (CERN, DESY, FNAL)**
 - Allows the study of MiP response with position information through an external tracker

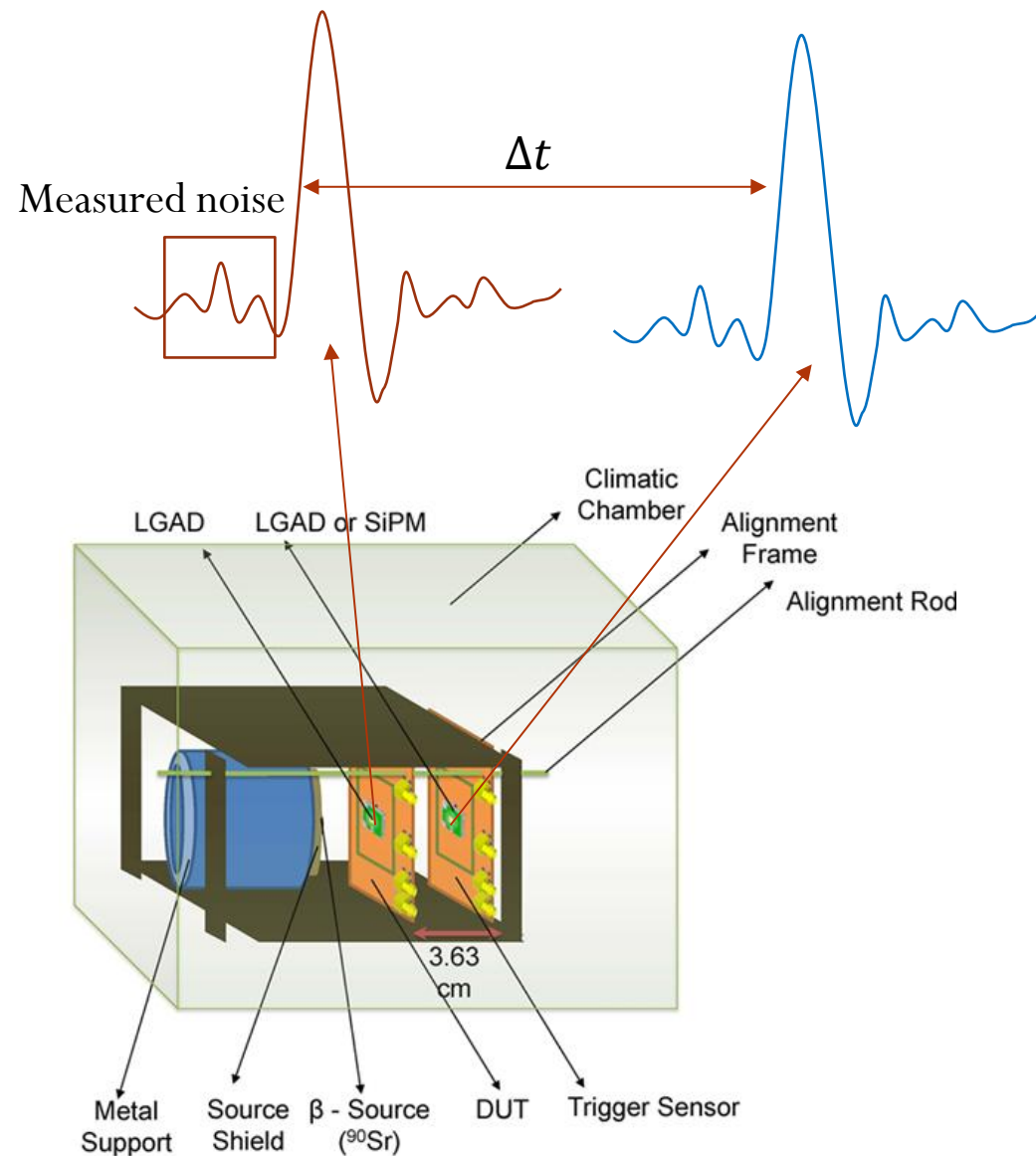
Sensor testing – IV/CV

- Capacitance over voltage (CV)
 - Study doping concentration profile and full depletion of the sensor
 - Doping profile can be extracted from the $1/C^2$ derivative
- Study of the “foot” for LGADs on $1/C^2$
 - $1/C^2$ is flat until depletion of multiplication layer because of the high doping concentration
 - Proportional to gain layer active concentration
- Bulk doping concentration proportional to the derivative of $1/C^2$ before depletion



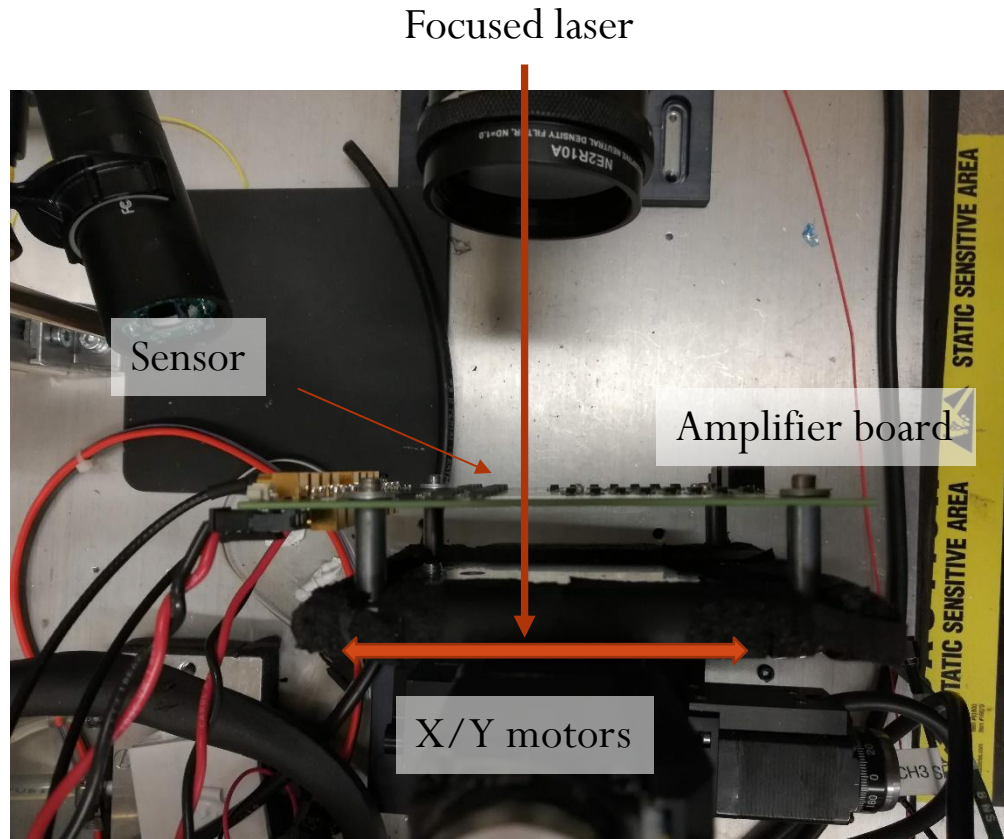
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 - Trigger with known performance
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- **Collected charge**
- **Time resolution:** sigma of time difference between trigger sensor (with known time resolution) and DUT,
- **Gain:** collected charge divided by collected charge in same thickness PiN
- **Signal to Noise ratio**

Sensor testing – Laser TCT setup

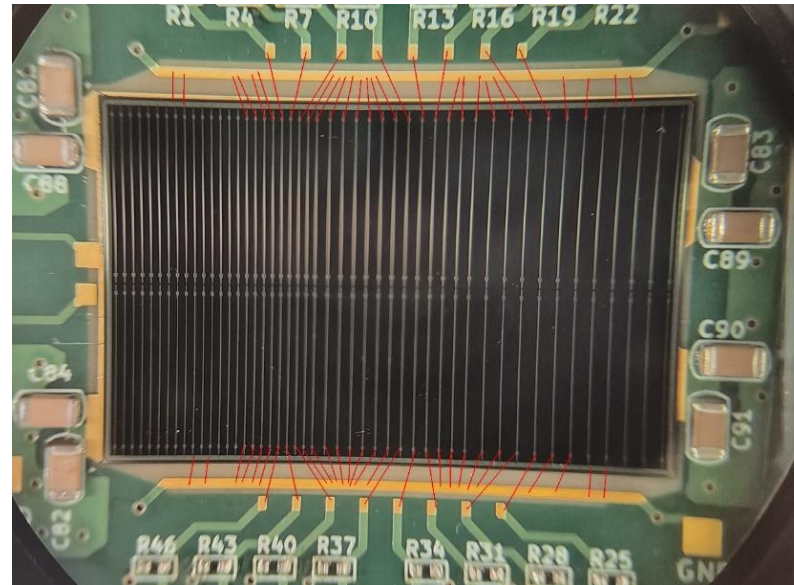
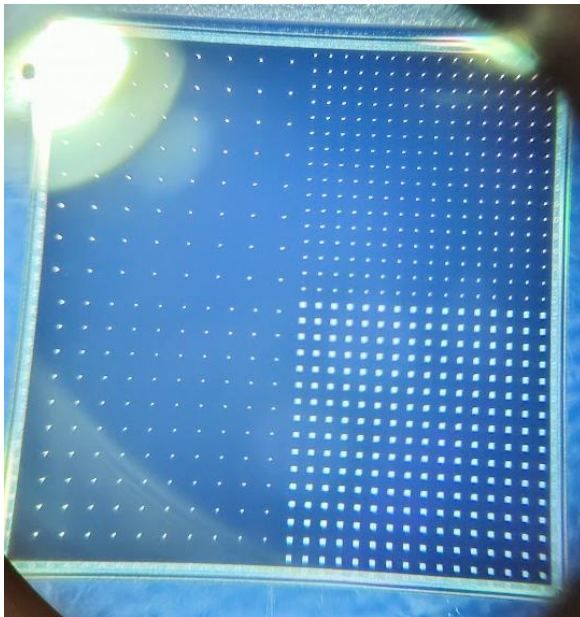


- Sensors are mounted on a multi-channel analog amplifier board with bandwidth ~ 1 GHz
- Response is readout by 2 GHz/20 Gs oscilloscope
- **IR laser (1064 nm)** mimics charge deposit of a Minimum Ionizing Particle (MiP)
 - Focused laser beam with spot width ~ 20 μm
- Amplifier board is mounted on X/Y moving stages
 - Charge injection as a function of position
- Metal is not transparent to IR so no response can be seen when laser is on top of metal
 - Only the sensor response in-between metal pads is visible

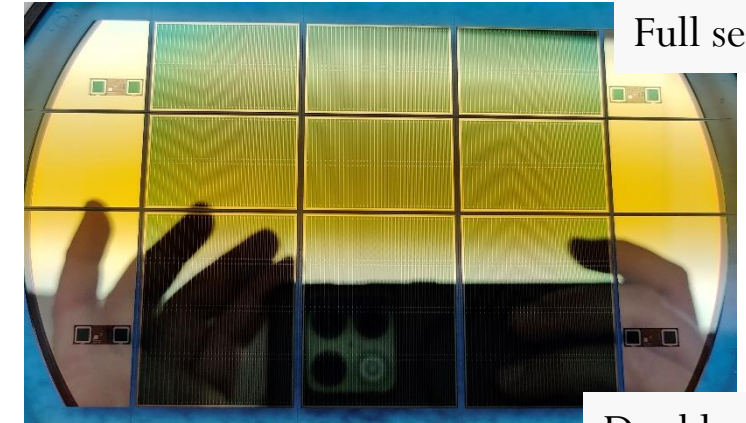


HPK s16694 production – 2024/2025

- ePIC full-size production of HPK strip and pixel AC-LGADs
 - Multi-pitch and multi-electrode size
- 8 strip wafers, 50um and 30um thick
- 4 pixel wafers, 30um and 20um thick
- Fully tested electrically and sample tested with laser and test beams
 - Measured parameters variation

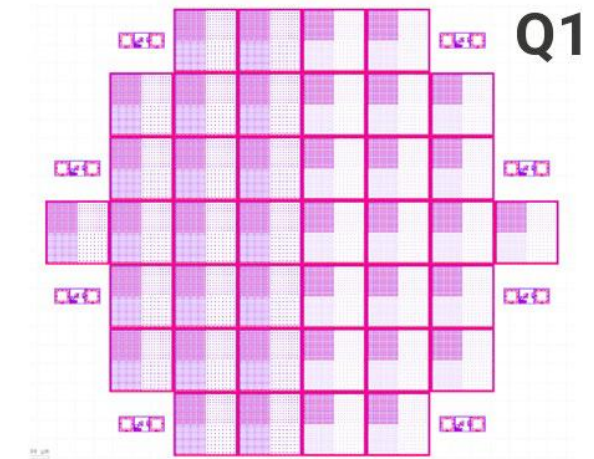


Half sensors



Full sensors

Double sensors



HPK Sensor production for pixel ongoing, first trials with EICROC1 when available (Q4 2025)